

Product Summary

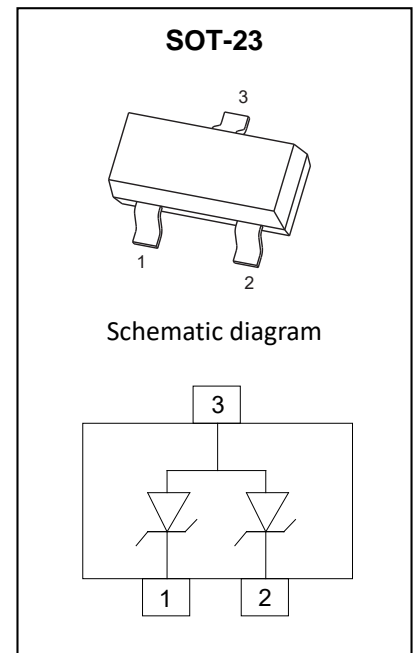
The GESDN36VC2 is an uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The dual-junction common-anode design allows the user to protect one bidirectional data line or two.

Feature

- Small package for use in portable electronics
- Low reverse clamping voltage
- Low leakage current
- Fast response time <1ns
- Meets MSL 1 Requirements
- IEC 61000-4-2 Level 4 ESD protection

Application

- Data lines
- Industrial Controls
- Cellular handsets AND accessories
- Portable instrumentation
- Peripherals
- Notebook Computers
- Set-Top Box
- Projection TV



Absolute Maximum Ratings ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
IEC 61000-4-2 ESD Voltage Air Model	$V_{\text{ESD}}^{1)}$	± 15	kV
IEC 61000-4-2 ESD Voltage Contact Model		± 8	
JESD22-A114-B ESD Voltage Per Human Body Model		± 8	
ESD Voltage Machine Model		± 0.4	
Peak Pulse Power	$P_{\text{PP}}^{2)}$	300	W
Peak Pulse Current	$I_{\text{PP}}^{2)}$	3	A
Lead Solder Temperature – Maximum (10 Second Duration)	T_L	260	$^{\circ}\text{C}$
Junction Temperature	T_j	150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-55~ +150	$^{\circ}\text{C}$

- 1) Device stressed with ten non-repetitive ESD pulses.
- 2) Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC61000-4-5.

ESD standards compliance

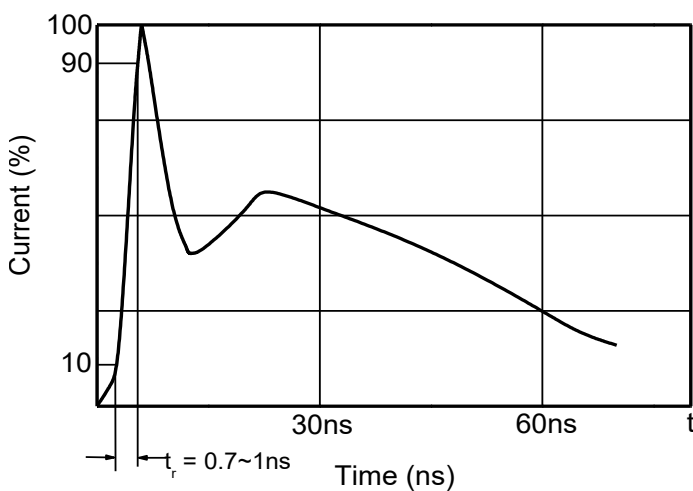
IEC61000-4-2 Standard

Contact Discharge		Air Discharge	
Level	Test Voltage kV	Level	Test Voltage kV
1	2	1	2
2	4	2	4
3	6	3	8
4	8	4	15

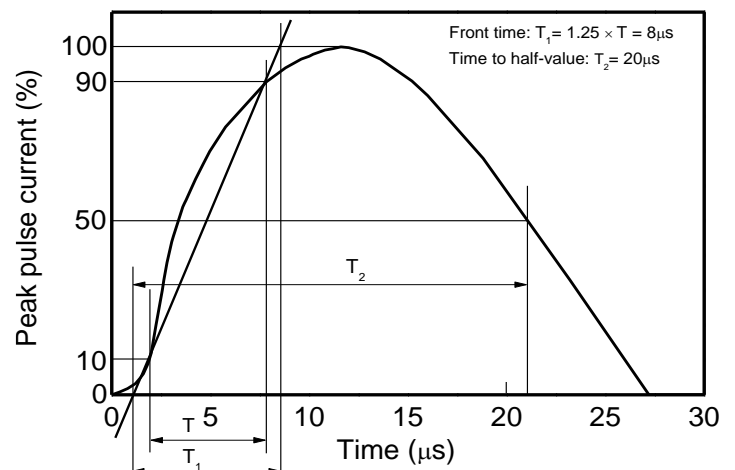
JESD22-A114-B Standard

ESD Class	Human Body Discharge V
0	0~249
1A	250~499
1B	500~999
1C	1000~1999
2	2000~3999
3A	4000~7999
3B	8000~15999

Contact discharge current waveform per IEC61000-4-2

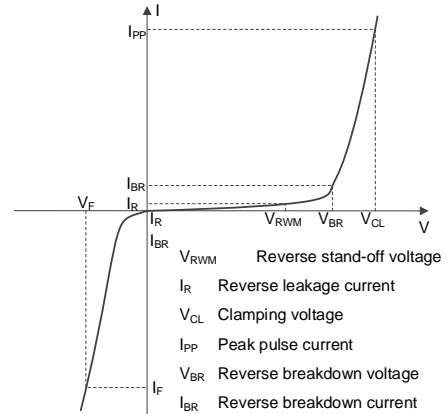


8/20 μs waveform per IEC61000-4-5



Electrical Parameter

Symbol	Parameter
V _C	Clamping Voltage @ I _{PP}
I _{PP}	Peak Pulse Current
V _{BR}	Breakdown Voltage @ I _T
I _T	Test Current
I _R	Reverse Leakage Current @ V _{RWM}
V _{RWM}	Reverse Standoff Voltage



V-I characteristics for a Uni-directional TVS

Electrical Characteristics (Ta=25°C unless otherwise specified)

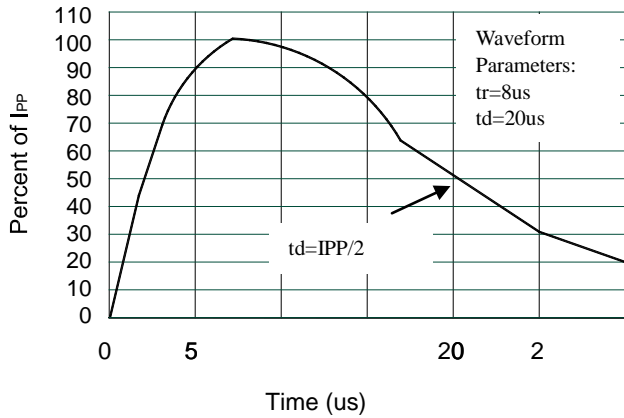
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse stand-off voltage	V _{RWM} ¹⁾				36	V
Reverse leakage current	I _R	V _{RWM} =36V			1	uA
Breakdown voltage	V _{BR}	I _T =1mA	40			V
Clamping voltage	V _C ²⁾	I _{PP} =1A		60		V
Junction capacitance	C _J	V _R =0V, f=1MHz		40	45	pF

1) Other voltages available upon request.

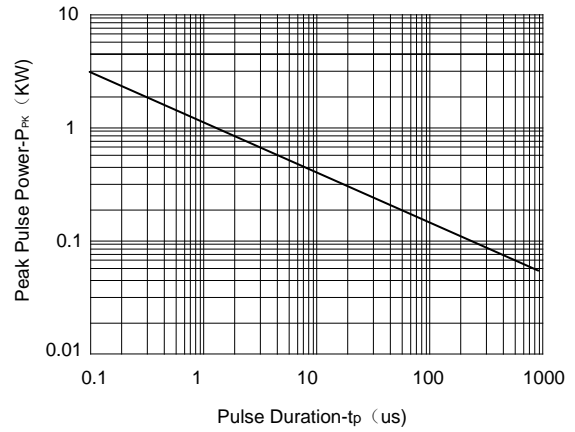
2) Non-repetitive current pulse 8/20μs exponential decay waveform according to IEC61000-4-5

Typical Characteristics

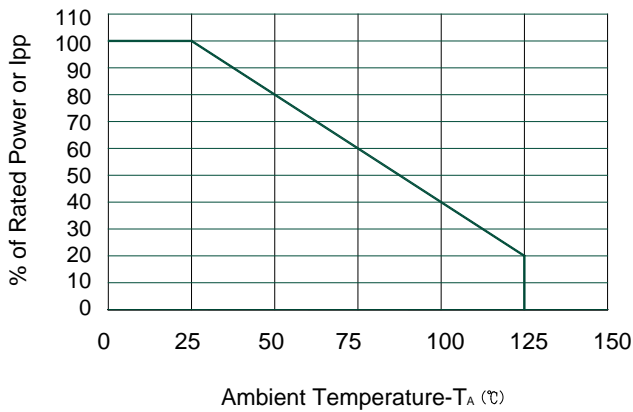
Pulse Waveform



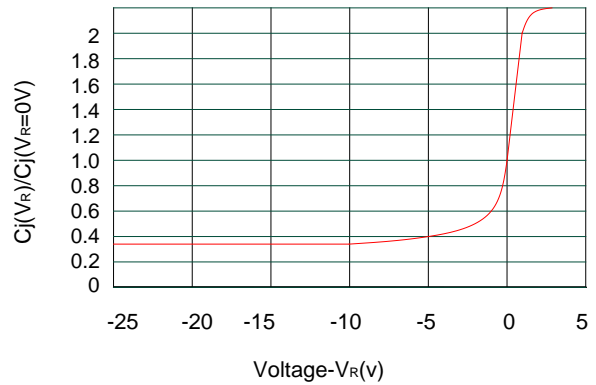
Non-Repetitive Peak Pulse Power vs. Pulse Time



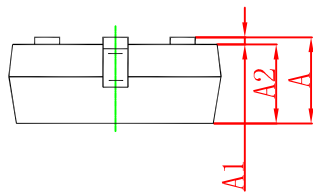
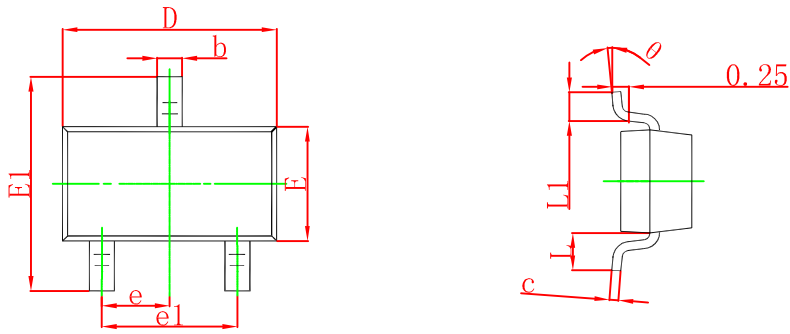
Power Derating Curve



Junction Capacitance vs. Reverse Voltage



SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
theta	0°	8°	0°	8°